

Pin Descriptions

Pin Number	Pin Name	Function
1	SW	Switch Pin. Connect inductor/freewheeling diode here, minimizing track length at this pin to reduce EMI.
2	GND	GND Pin
3	CTRL	Dimming and On/Off Control Input. <ul style="list-style-type: none"> Leave floating for normal operation. ($V_{CTRL} = V_{REF} = 2.5V$ giving nominal average output current $I_{OUTnom} = 0.1/R_S$) Drive to voltage below 0.4V to turn off output current Drive with DC voltage ($0.5V < V_{CTRL} < 2.5V$) to adjust output current from 20% to 100% of I_{OUTnom} A PWM signal (low level $\leq 0.4V$ and high level > 2.6; transition times less than 1us) allows the output current to be adjusted below the level set by the resistor connected to SET input pin.
4	SET	Set Nominal Output Current Pin. Configure the output current of the device.
5	V_{IN}	Input Supply Pin. Must be locally decoupled to GND with $\geq 2.2\mu F$ X7R ceramic capacitor – see applications section for more information.

Absolute Maximum Ratings (@ $T_A = +25^\circ C$, unless otherwise specified.)

Symbol	Parameter	Ratings	Unit
ESD HBM	Human Body Model ESD Protection	2.5	kV
ESD MM	Machine Model ESD Protection	200	V
V_{IN}	Continuous V_{IN} Pin Voltage Relative to GND	-0.3 to 40	V
V_{SET}	SET Pin Voltage Relative to V_{IN} Pin	-5 to +0.3	V
V_{SW}	SW Voltage Relative to GND	-0.3 to 40	V
V_{CTRL}	CTRL Pin Input Voltage	-0.3 to 6	V
I_{SW-DC}	DC or RMS Switch current	1.25	A
I_{SW-PK}	Peak Switch Current (<10%)	2.5	A
T_J	Junction Temperature	150	$^\circ C$
T_{LEAD}	Lead Temperature Soldering	300	$^\circ C$
T_{ST}	Storage Temperature Range	-65 to +150	$^\circ C$

Caution: Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

Semiconductor devices are ESD sensitive and may be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices

Recommended Operating Conditions (@ $T_A = +25^\circ C$, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V_{IN}	Operating Input Voltage relative to GND	6.0	36	V
V_{CTRLH}	Voltage High for PWM Dimming Relative to GND	2.6	5.5	V
V_{CTRLDC}	Voltage Range for 20% to 100% DC Dimming Relative to GND	0.5	2.5	V
V_{CTRLLL}	Voltage Low for PWM Dimming Relative to GND	0	0.4	V
I_{SW}	Continuous Switch Current	—	1	A
T_J	Junction Temperature Range	-40	125	$^\circ C$

Electrical Characteristics ($V_{IN} = 12$, @ $T_A = +25^{\circ}\text{C}$, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{INSU}	Internal Regulator Start Up Threshold	V_{IN} rising			5.9	V
V_{INSH}	Internal Regulator Hysteresis Threshold	V_{IN} falling	100		300	mV
I_Q	Quiescent Current	Output not switching (Note 4)			350	μA
I_S	Input Supply Current	CTRL pin floating $f = 250\text{kHz}$		1.8	5	mA
V_{TH}	Set Current Threshold Voltage		95	100	105	mV
V_{TH-H}	Set Threshold Hysteresis			± 20		mV
I_{SET}	SET Pin Input Current	$V_{SET} = V_{IN} - 0.1$		16	22	μA
R_{CTRL}	CTRL Pin Input Resistance	Referred to internal reference		50		k Ω
V_{REF}	Internal Reference Voltage			2.5		V
$R_{DS(on)}$	On Resistance of SW MOSFET	$I_{SW} = 1\text{A}$		0.25	0.4	Ω
$I_{SW_Leakage}$	Switch Leakage Current	$V_{IN} = 30\text{V}$			0.5	μA
f_{OSC}	Switching Frequency				1	MHz
θ_{JA}	Thermal Resistance Junction-to-Ambient (Note 5)	SOT25 (Note 6)		250		$^{\circ}\text{C/W}$
Ψ_{JB}	Thermal Resistance Junction-to-Lead (Note 7)	SOT25		50		

- Notes:
- AL8805 does not have a low power standby mode but current consumption is reduced when output switch is inhibited: $V_{SENSE} = 0\text{V}$. Parameter is tested with $V_{CTRL} \leq 2.5\text{V}$.
 - Refer to figure 34 for the device derating curve.
 - Test condition for SOT25: Device mounted on FR-4 PCB (25mm x 25mm 1oz copper, minimum recommended pad layout on top layer and thermal vias to bottom layer ground plane. For better thermal performance, larger copper pad for heat-sink is needed.
 - As SOT25 doesn't have an exposed tab or exposed pad the majority of heat flow is through pin 2 down to ground.

Typical Performance Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

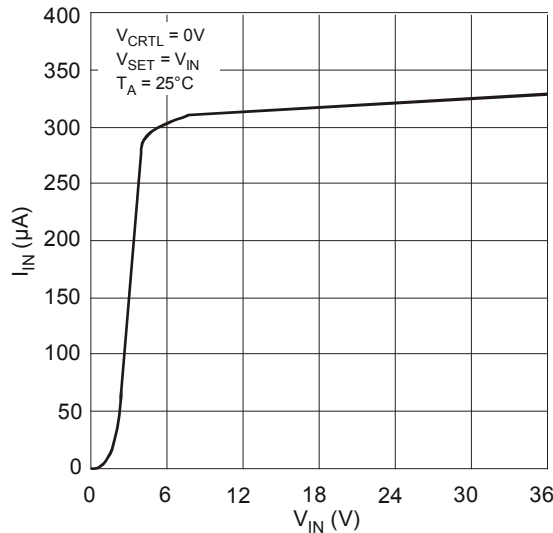


Figure 1 Supply Current (not switching) vs. Input Voltage

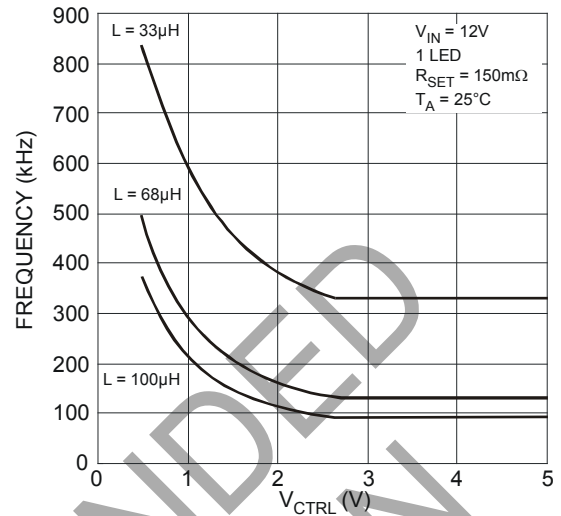


Figure 2 Switching Frequency vs. V_{CTRL}

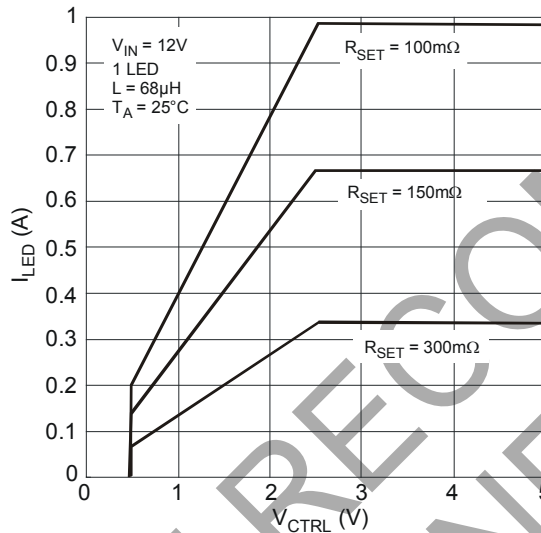


Figure 3 LED Current vs. V_{CTRL}

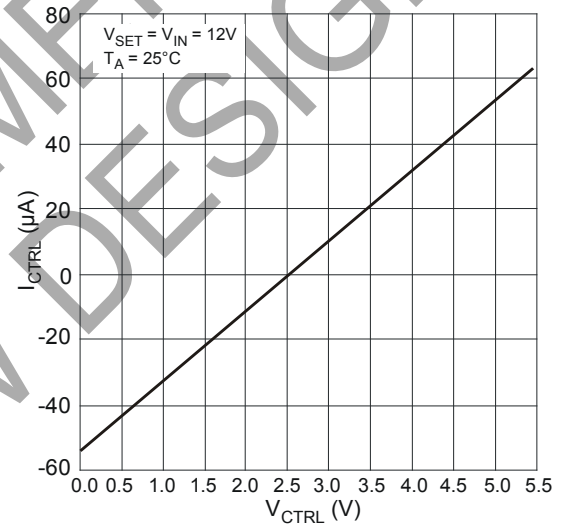


Figure 4 I_{CTRL} vs. V_{CTRL}

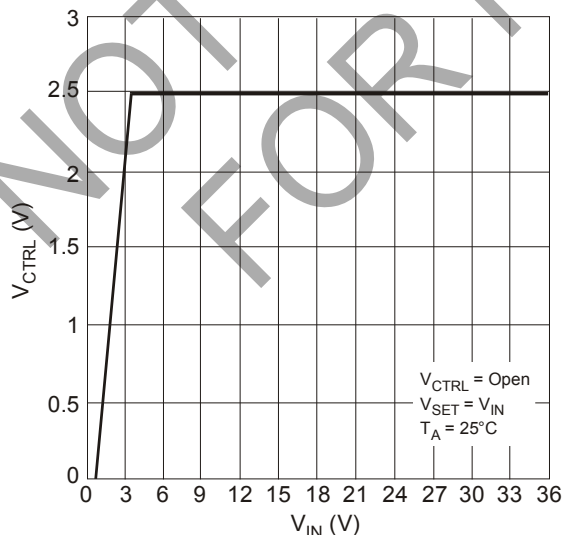


Figure 5 V_{CTRL} vs. Input Voltage
(CTRL Pin Open Circuit)

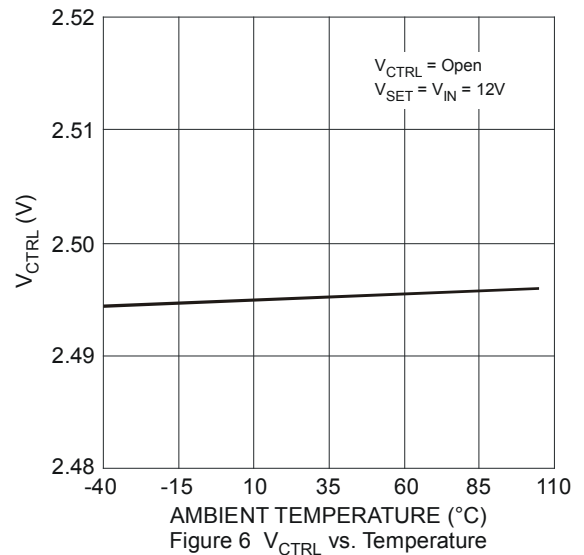
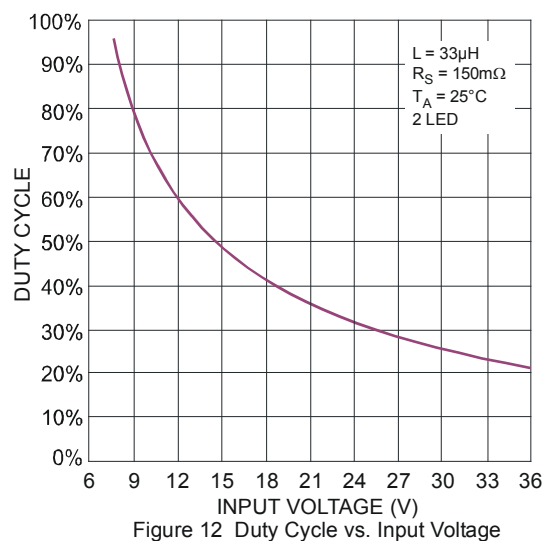
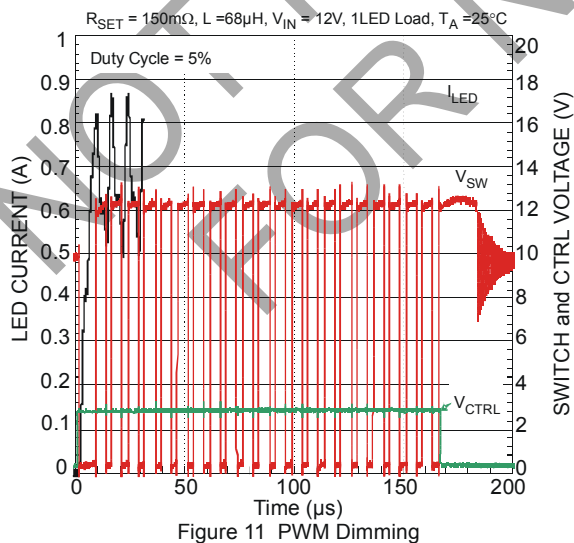
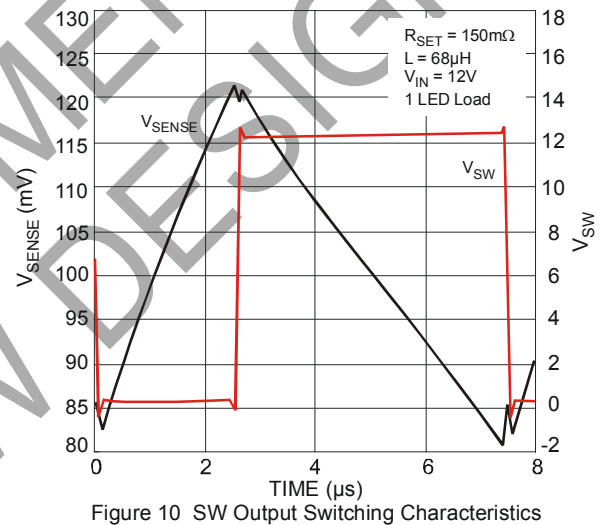
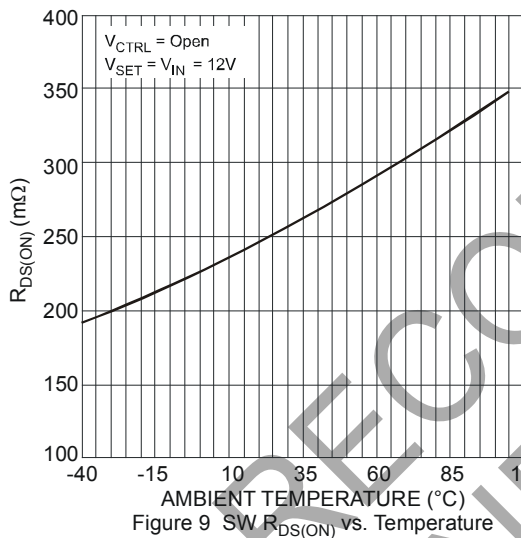
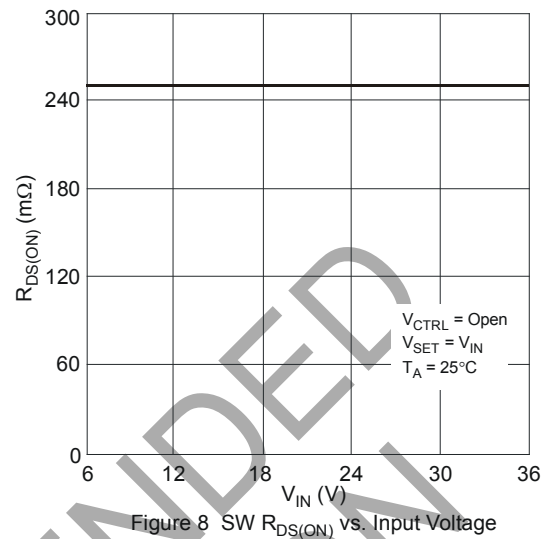
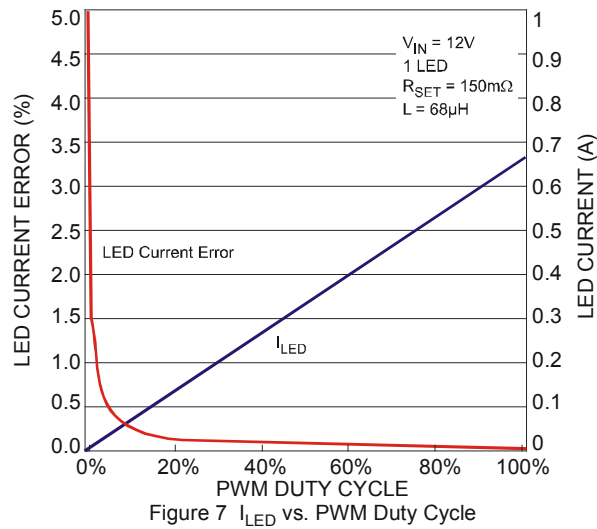


Figure 6 V_{CTRL} vs. Temperature

Typical Performance Characteristics (cont.) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Typical Performance Characteristics (cont.) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

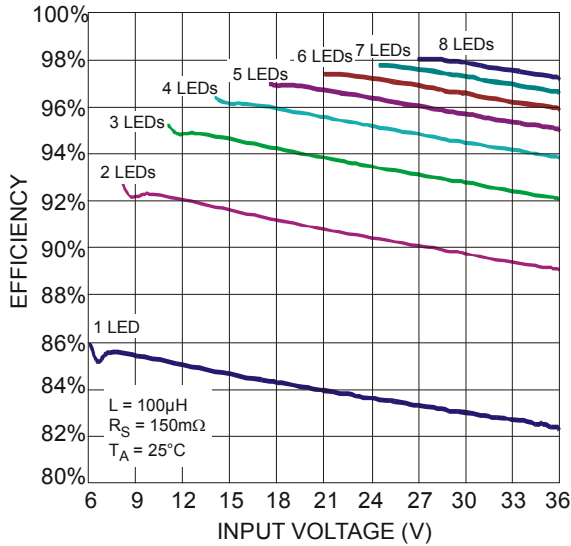


Figure 13 Efficiency vs. Input Voltage

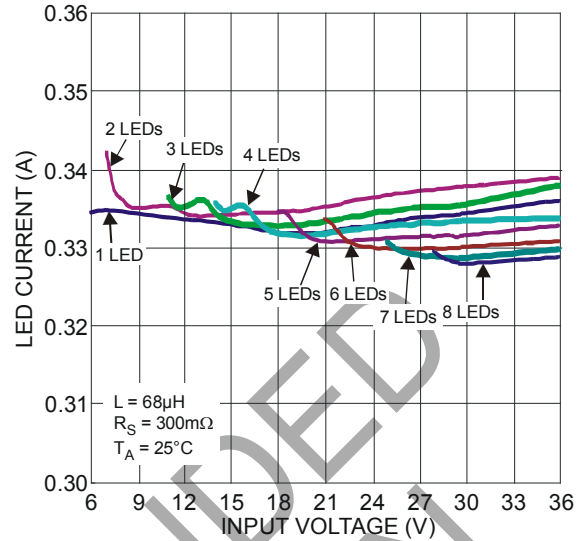


Figure 14 330mA LED Current vs. Input Voltage

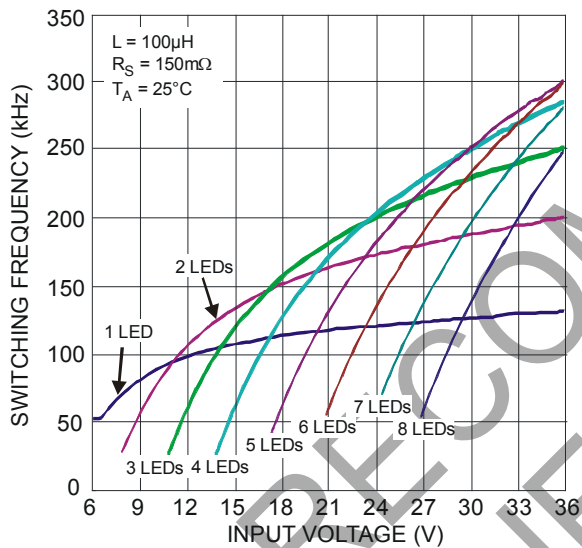


Figure 15 Switching Frequency vs. Input Voltage

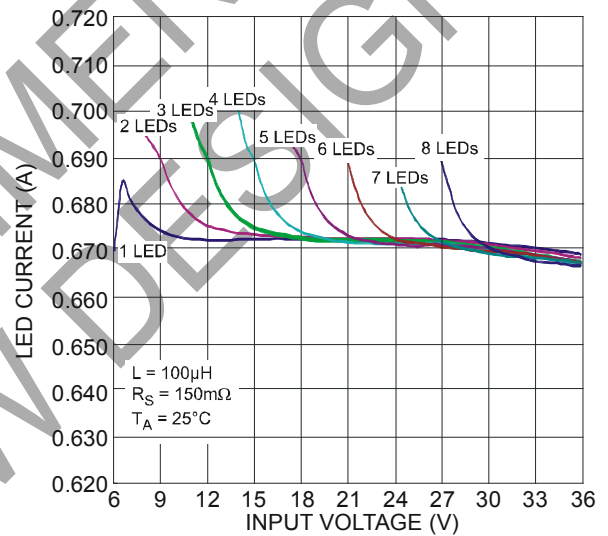


Figure 16 670mA LED Current vs. Input Voltage

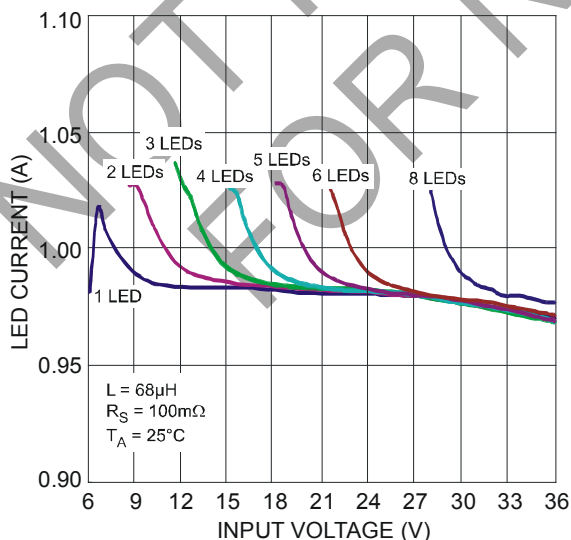


Figure 17 1A LED Current vs. Input Voltage

Typical Performance Characteristics (cont.) (670mA LED Current) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

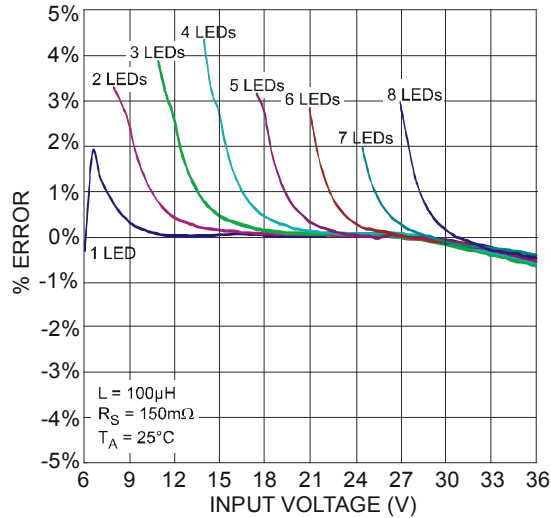


Figure 18 LED Current Deviation vs. Input Voltage

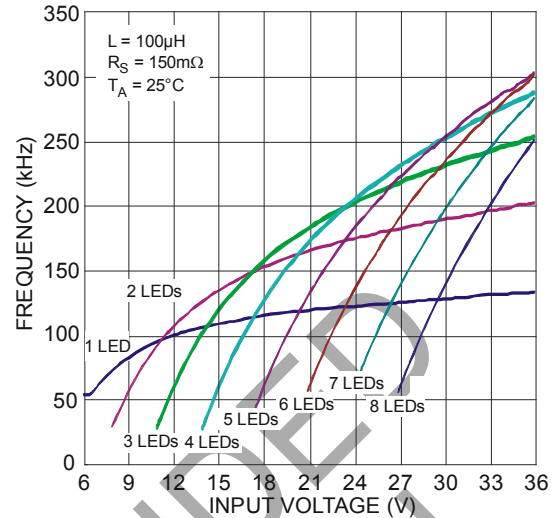


Figure 19 Switching Frequency vs. Input Voltage

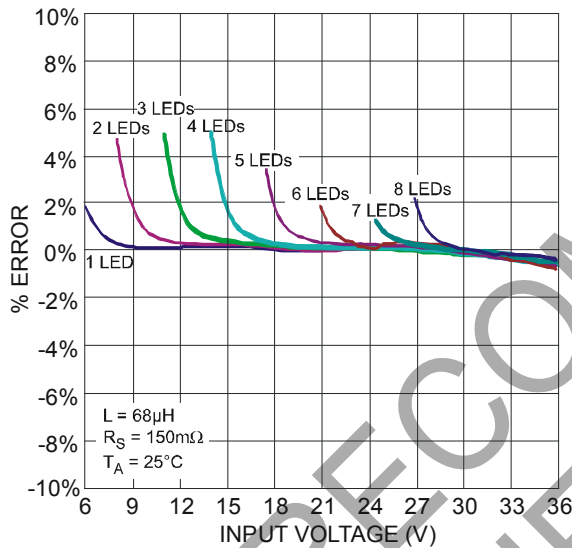


Figure 20 LED Current Deviation vs. Input Voltage

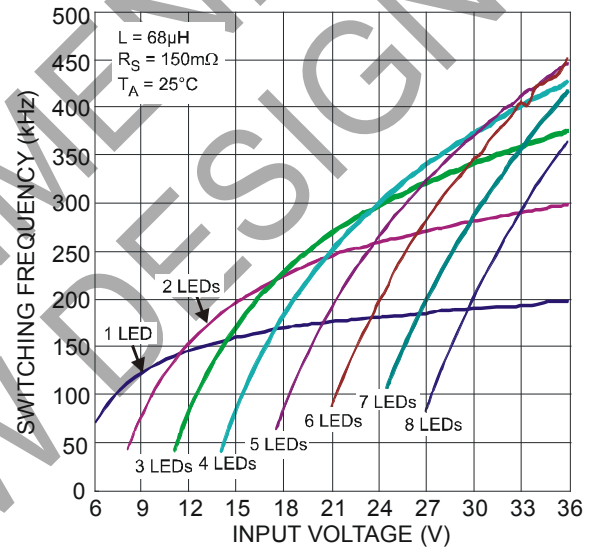


Figure 21 Switching Frequency vs. Input Voltage

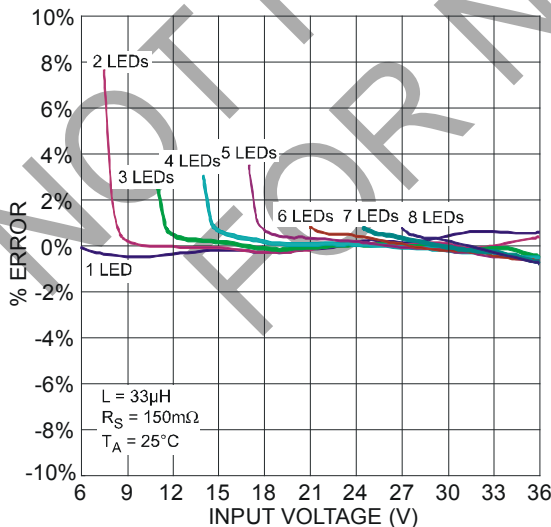


Figure 22 LED Current Deviation vs. Input Voltage

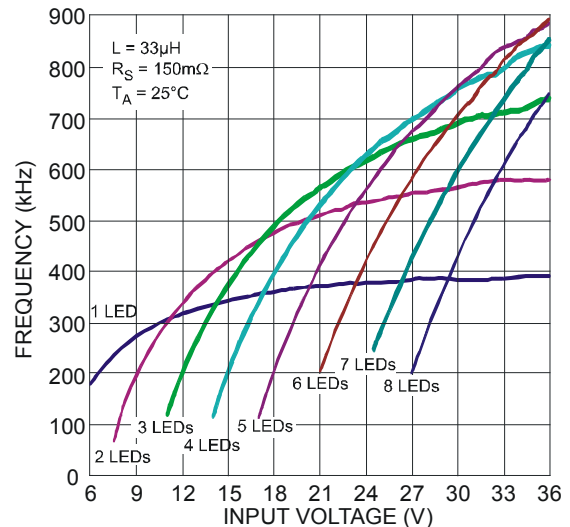


Figure 23 Switching Frequency vs. Input Voltage

Typical Performance Characteristics (cont.) (1A LED Current) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

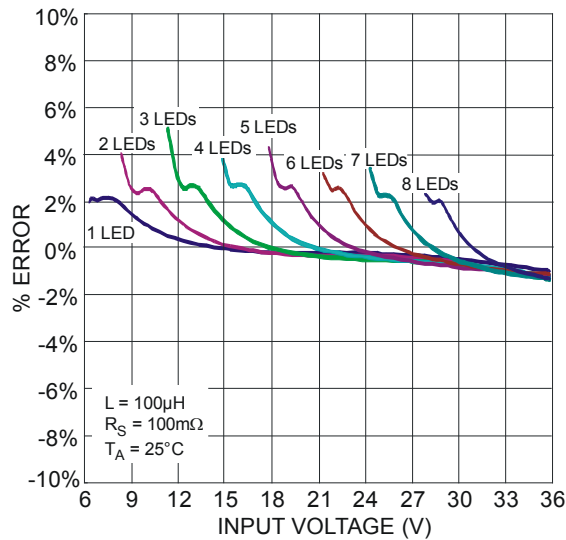


Figure 24 LED Current Deviation vs. Input Voltage

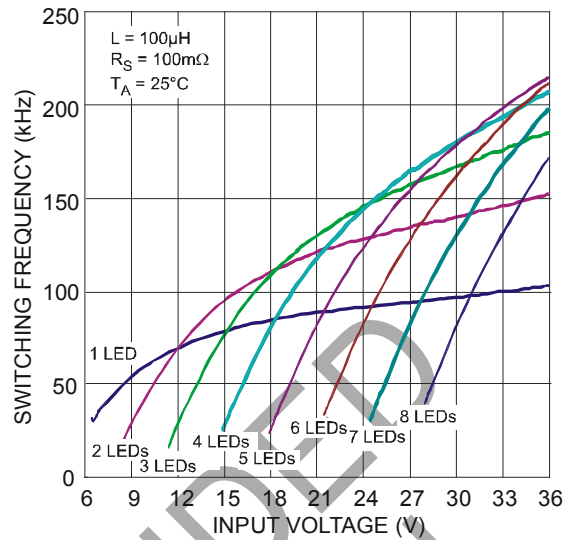


Figure 25 Switching Frequency vs. Input Voltage

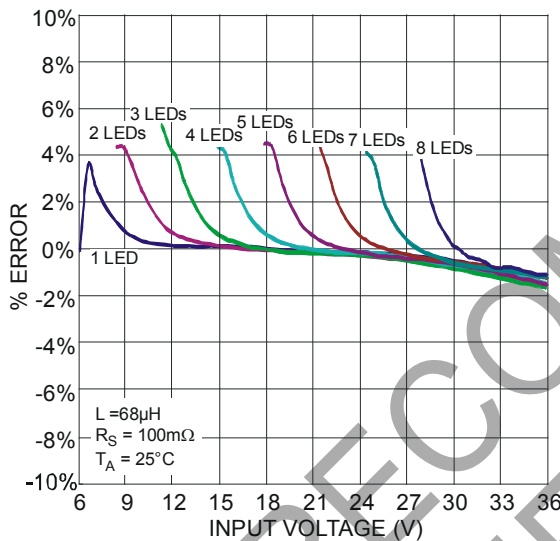


Figure 26 LED Current Deviation vs. Input Voltage

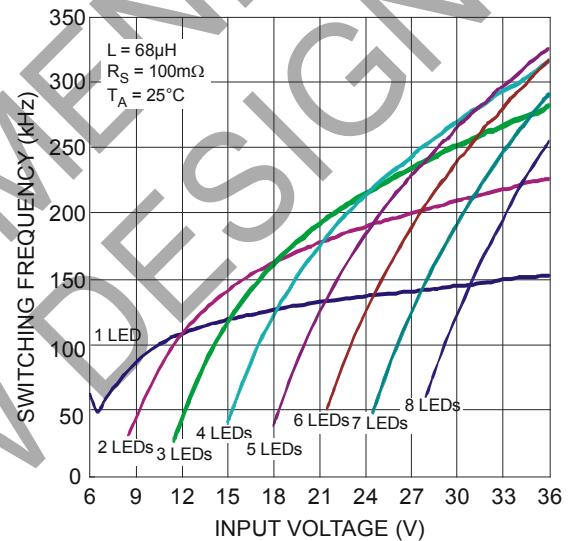


Figure 27 Switching Frequency vs. Input Voltage

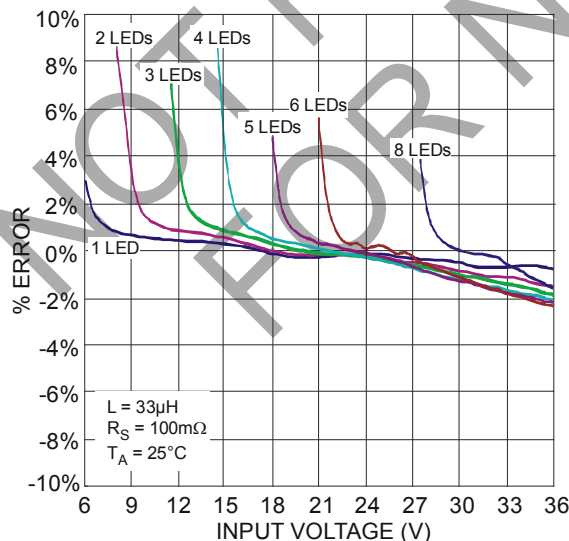


Figure 28 LED Current Deviation vs. Input Voltage

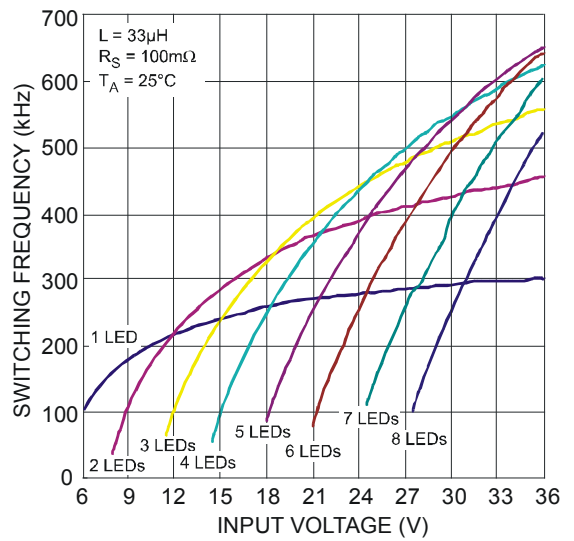


Figure 29 Switching Frequency vs. Input Voltage

Application Information

AL8805 Operation

In normal operation, when voltage is applied at +V_{IN}, the AL8805 internal switch is turned on. Current starts to flow through sense resistor R₁, inductor L1, and the LEDs. The current ramps up linearly, and the ramp rate is determined by the input voltage +V_{IN} and the inductor L1.

This rising current produces a voltage ramp across R₁. The internal circuit of the AL8805 senses the voltage across R₁ and applies a proportional voltage to the input of the internal comparator.

When this voltage reaches an internally set upper threshold, the internal switch is turned off. The inductor current continues to flow through R₁, L1, the LEDs and the schottky diode D1, and back to the supply rail, but it decays, with the rate of decay determined by the forward voltage drop of the LEDs and the schottky diode.

This decaying current produces a falling voltage at R₁, which is sensed by the AL8805. A voltage proportional to the sense voltage across R₁ is applied at the input of the internal comparator. When this voltage falls to the internally set lower threshold, the internal switch is turned on again. This switch-on-and-off cycle continues to provide the average LED current set by the sense resistor R₁.

LED Current Control

The LED current is controlled by the resistor R₁ in Figure 30.

Connected between V_{IN} and SET the nominal average output current in the LED(s) is defined as:

$$I_{LED} = \frac{V_{THD}}{R_{SET}}$$

If the CTRL pin is driven by an external voltage (higher than 0.4V and lower than 2.5V), the average LED current is:

$$I_{LED} = \frac{V_{CTRL}}{V_{REF}} \frac{V_{THD}}{R_{SET}}$$

For example for a desired LED current of 660mA and a default voltage V_{CTRL}=2.5V the resulting resistor is:

$$R_{SET} = \frac{V_{THD}}{I_{LED}} \frac{V_{CTRL}}{V_{REF}} = \frac{0.1}{0.66} \frac{2.5}{2.5} \approx 150m\Omega$$

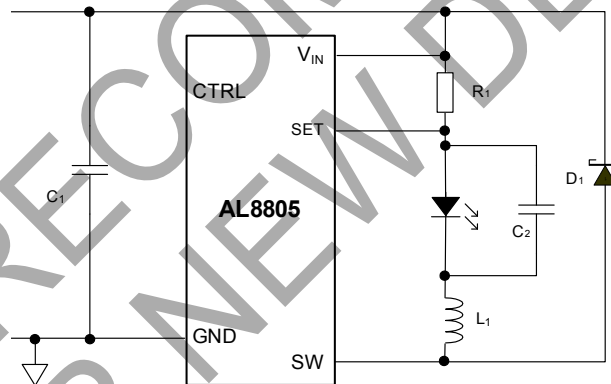


Figure 30 Typical Application Circuit

DC Dimming

The CTRL pin can be driven by an external DC voltage (V_{CTRL}), to adjust the output current to a value below the nominal average value defined by R_{SET}. The LED current decreases linearly with the CTRL voltage when 0.5V ≤ V_{CTRL} ≤ 2.5V, as in Figure 2 for 4 different current levels.

When the CTRL voltage falls below the threshold, 0.4V, the output switch is turned off which allows PWM dimming.

Note that 100% brightness setting corresponds to V_{CTRL} = V_{REF}, nominally 2.5V. For any voltage applied on the CTRL pin that is higher than V_{REF}, the device will not overdrive the LED current and will still set the current according to the equation V_{CTRL} = V_{REF}.

Application Information (cont.)

PWM Dimming

LED current can be adjusted digitally, by applying a low frequency Pulse Width Modulated (PWM) logic signal to the CTRL pin to turn the device on and off. This will produce an average output current proportional to the duty cycle of the control signal. In particular, a PWM signal with a max resolution of 10bit can be applied to the CTRL pin to change the output current to a value below the nominal average value set by resistor R_{SET} . To achieve this resolution the PWM frequency has to be lower than 500Hz, however higher dimming frequencies can be used, at the expense of dimming dynamic range and accuracy.

Typically, for a PWM frequency of 500Hz the accuracy is better than 1% for PWM ranging from 1% to 100%.

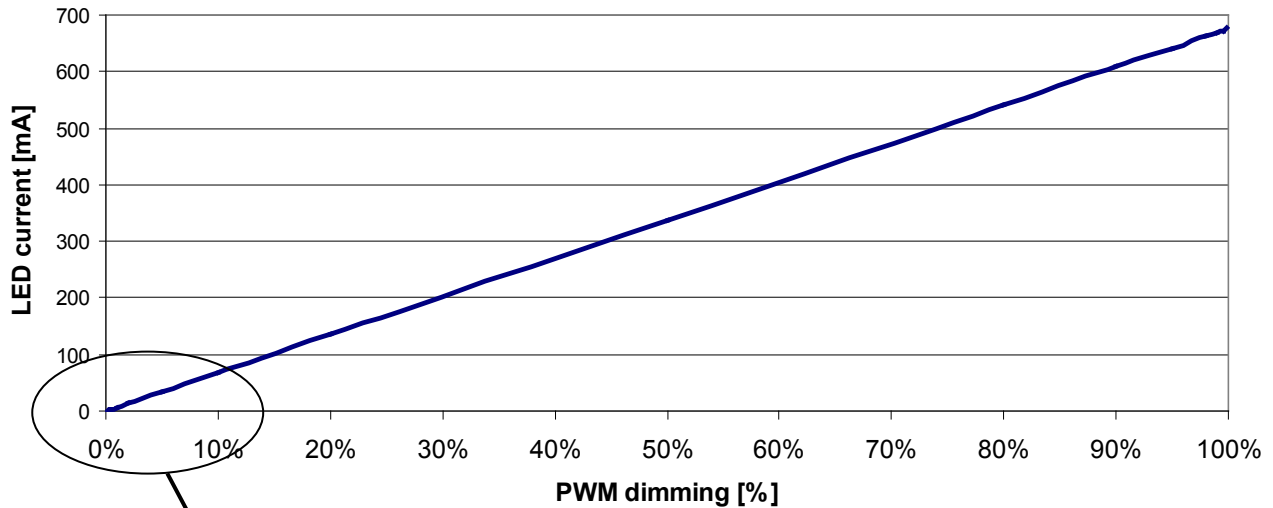


Figure 31 PWM Dimming at 500Hz

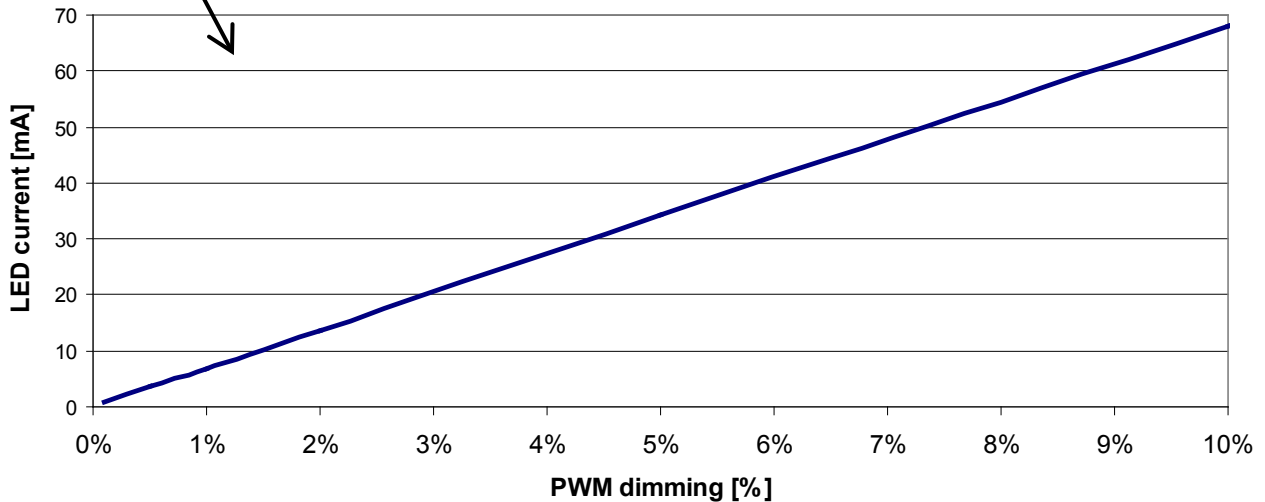
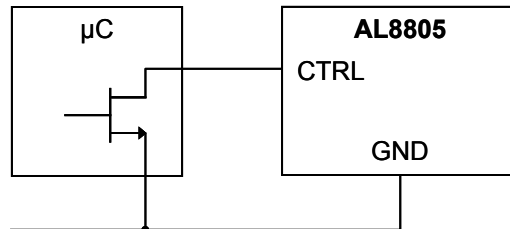


Figure 32 Low Duty Cycle PWM Dimming at 500Hz

The CTRL pin is designed to be driven by both 3.3V and 5V logic levels directly from a logic output with either an open drain output or push-pull output stage.



Application Information (cont.)

Soft Start

The AL8805 does not have in-built soft-start action – this provides very fast turn off of the output the stage improving PWM dimming accuracy; nonetheless, adding an external capacitor from the CTRL pin to ground will provide a soft-start delay. This is achieved by increasing the time taken for the CTRL voltage to rise to the turn-on threshold and by slowing down the rate of rise of the control voltage at the input of the comparator. Adding a capacitor increases the time taken for the output to reach 90% of its final value, this delay is 0.1ms/nF, but will impact on the PWM dimming accuracy depending on the delay introduced.

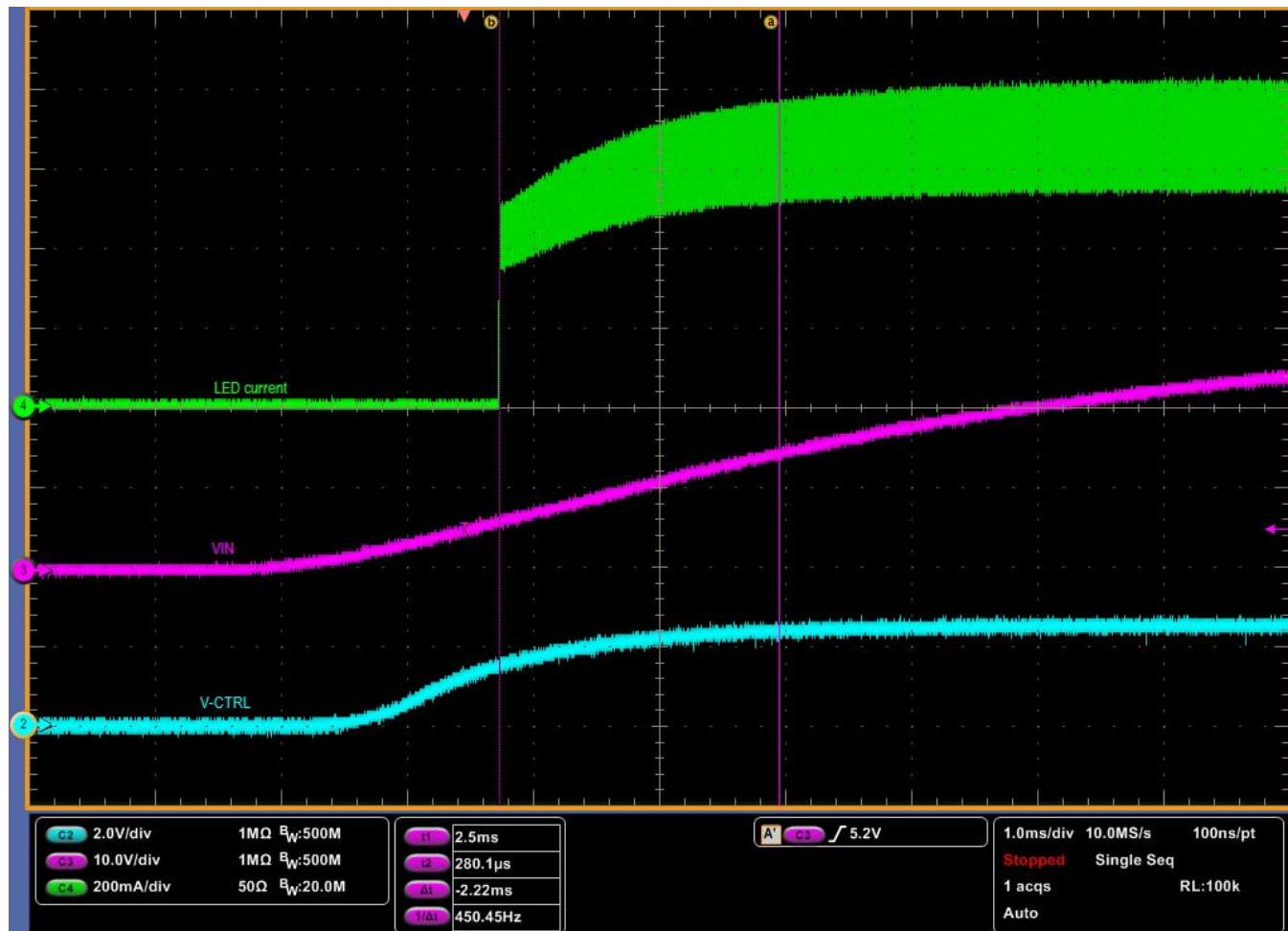


Figure 33 Soft Start with 22nF Capacitor on CTRL Pin ($V_{IN} = 36V$, $I_{LED} = 667mA$, 1 LED)

Reducing Output Ripple

Peak to peak ripple current in the LED(s) can be reduced, if required, by shunting a capacitor C2 across the LED(s) as shown already in the circuit schematic.

A value of 1μF will reduce the supply ripple current by a factor three (approx.). Proportionally lower ripple can be achieved with higher capacitor values. Note that the capacitor will not affect operating frequency or efficiency, but it will increase start-up delay, by reducing the rate of rise of LED voltage. By adding this capacitor the current waveform through the LED(s) changes from a triangular ramp to a more sinusoidal version without altering the mean current value.

Capacitor Selection

The small size of ceramic capacitors makes them ideal for AL8805 applications. X5R and X7R types are recommended because they retain their capacitance over wider voltage and temperature ranges than other types such as Z5U.

A 2.2μF input capacitor is sufficient for most intended applications of AL8805; however a 4.7μF input capacitor is suggested for input voltages approaching 36V.

Application Information (cont.)

Diode Selection

For maximum efficiency and performance, the rectifier (D1) should be a fast low capacitance Schottky diode with low reverse leakage at the maximum operating voltage and temperature. The Schottky diode also provides better efficiency than silicon PN diodes, due to a combination of lower forward voltage and reduced recovery time.

It is important to select parts with a peak current rating above the peak coil current and a continuous current rating higher than the maximum output load current. In particular, it is recommended to have a diode voltage rating at least 15% higher than the operating voltage to ensure safe operation during the switching and a current rating at least 10% higher than the average diode current. The power rating is verified by calculating the power loss through the diode.

Schottky diodes, e.g. B240 or B140, with their low forward voltage drop and fast reverse recovery, are the ideal choice for AL8805 applications.

Thermal and Layout Considerations

For continuous conduction mode of operation, the absolute maximum junction temperature must not be exceeded. The maximum power dissipation depends on several factors: the thermal resistance of the IC package θ_{JA} , PCB layout, airflow surrounding the IC, and difference between junction and ambient temperature.

The maximum power dissipation can be calculated using the following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

where

$T_{J(MAX)}$ is the maximum operating junction temperature,

T_A is the ambient temperature, and

θ_{JA} is the junction to ambient thermal resistance.

The recommended maximum operating junction temperature, T_J , is +125°C and so maximum ambient temperature is determined by the AL8805's junction to ambient thermal resistance, θ_{JA} .

θ_{JA} , is layout dependent and the AL8805's θ_{JA} on a 25 x 25mm single layer PCB with 1oz copper standing in still air is approximately +250°C/W (+160°C/W on a four-layer PCB).

The maximum power dissipation at $T_A = +25^\circ\text{C}$ can be calculated by the following formulas:

$$P_{D(MAX)} = (+125^\circ\text{C} - +25^\circ\text{C}) / (250^\circ\text{C/W}) = 0.4\text{W for single-layer PCB}$$

$$P_{D(MAX)} = (+125^\circ\text{C} - +25^\circ\text{C}) / (160^\circ\text{C/W}) = 0.625\text{W for standard four-layer PCB}$$

Figure 34, shows the power derating of the AL8805 on two (one single-layer and four-layer) different 25x25mm PCB with 1oz copper standing in still air.

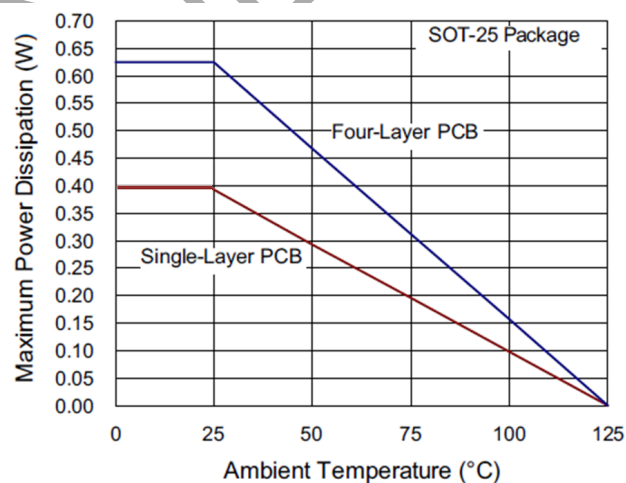


Figure 34 Derating Curve for Different PCB

Application Information (cont.)

Thermal and Layout Considerations

Figure 35 gives details about the PCB layout suggestions:

1. the capacitor C1 has to be placed as close as possible to V_{IN}
2. The sense resistor R1 has to be placed as close as possible to V_{IN} and SET
3. The D1 anode, the SW pin and the inductor have to be placed as close as possible to avoid ringing.

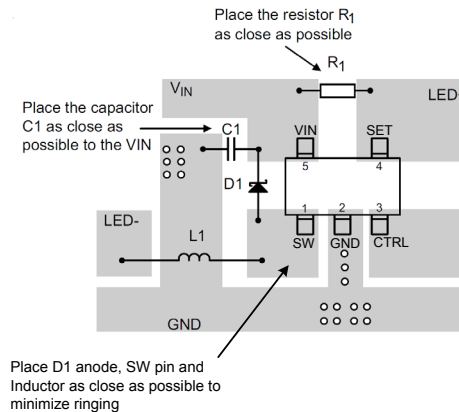


Figure 35 Recommended PCB Layout

Application Example

Typical application example for the AL8805 is the MR16 lamp. They typically operate from 12V_{DC} or 12V_{AC}, using conventional electromagnetic transformers or electronic transformers.

As a replacement in some halogen lamp applications LEDs offer a more energy efficient solution – providing no radiated heat and no Ultra Violet light.

This application example is intended to fit into the base connector space of an MR16 style LED lamp. The design has been optimized for part count and thermal performance for a single 3W LED in the Lens section.

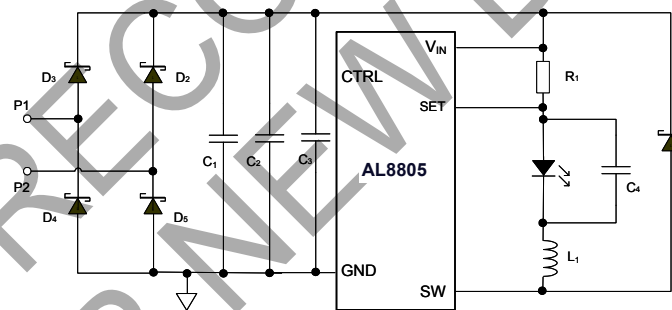


Figure 36 MR16 Schematic

An inductor choice of 33μH with saturation current higher than 1.1A, will limit the frequency variation between 230kHz and 350kHz over the whole input voltage variation (8V to 18V), and therefore represent the best choice for an MR16 solution also taking into account the size constraint of the lamp.

The AL8805 guarantee high level of performance both with 12V_{AC} and 12V_{DC} power supply.

The efficiency is generally higher than 81% and current regulation is better than 0.1mA/V in for a DC input voltage in the range from 8V to 18V. In table 1 can be found the bill of material of the MR16 application example.

Application Information (cont.)

In Figures 37 and 38 are displayed the top layer and the bottom layer of a typical PCB design for an MR16 solution.

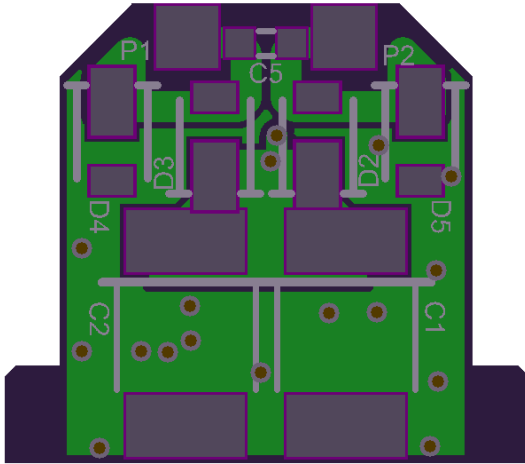


Figure 37 Top Layer

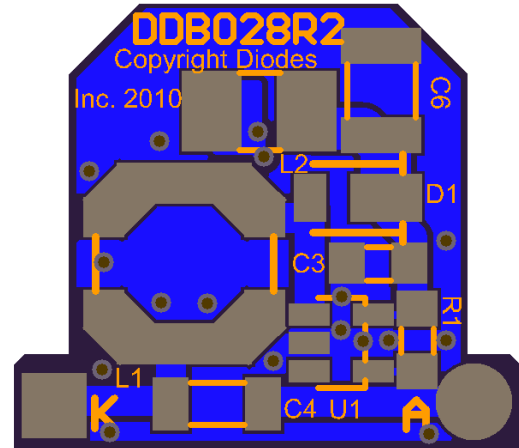


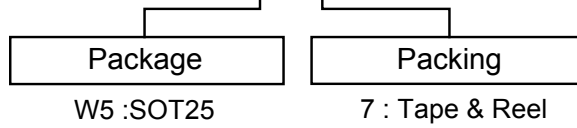
Figure 38 Bottom Layer

Table1 MR16 Application Example Bill of Material

Quantity	PCB Ident	Value	Description	Suggested Sources
1	U1	AL8805	LED Driver IC	Diodes Zetex
1	D1,	DFLS240L	freewheeling diode	Diodes Zetex
4	D2, D3, D4, D5	SBR2A40	Input bridge	Diodes Zetex
1	R1	0R15	Resistor, 0805, +/-1% <+/-300ppm Generic KOA SR732ATTDR150F	Kemet
1	C1	150uF 20V	SMD tantalum Kemet D case, T491X157K020AT	Kemet
0	C2	-	Not fitted	
1	C3	100nF >= 25V	X7R 0805 Generic Kemet C0805C104K5RAC (50v) NIC NMC0805X7R104K50TRPF (50v)	Kemet NIC Components
1	C4	1uF >= 25V	X7R 1206 Generic Kemet C1206105K5RAC7800 (50v) NIC NMC1206X7R105K50F (50v)	Kemet NIC Components
1	L1	33uH	LPS6235 - 333MLB	Coilcraft

Ordering Information

AL 8805 W5 - 7



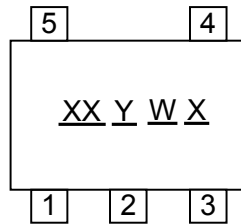
Device	Package Code	Packaging (Note 6)	7" Tape and Reel	
			Quantity	Part Number Suffix
AL8805W5-7	W5	SOT25	3000/Tape & Reel	-7



Note: 8. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at: <http://www.diodes.com/datasheets/ap02001.pdf>.

Marking Information

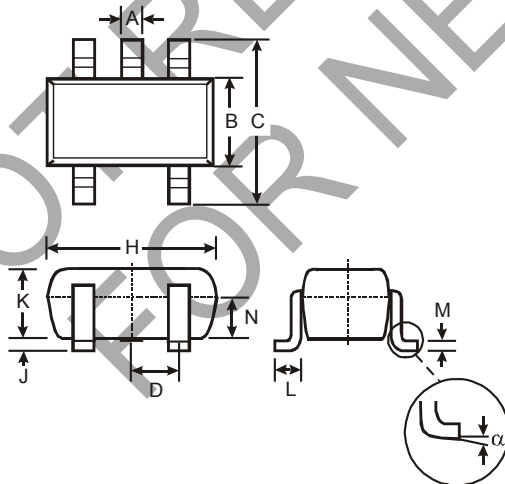
(Top View)



XX : Identification code
 Y : Year 0~9
 W : Week : A~Z : 1~26 week;
 a~z : 27~52 week; z represents
 52 and 53 week
 X : A~Z : Internal code

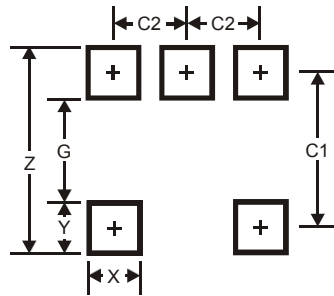
Part Number	Package	Identification Code
AL8805W5-7	SOT25	A6

Package Outline Dimensions (All dimensions in mm.)



SOT25			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

NOT RECOMMENDED
FOR NEW DESIGN

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